TOSHIBA Photocoupler GaAs Ired & Photo−Transistor

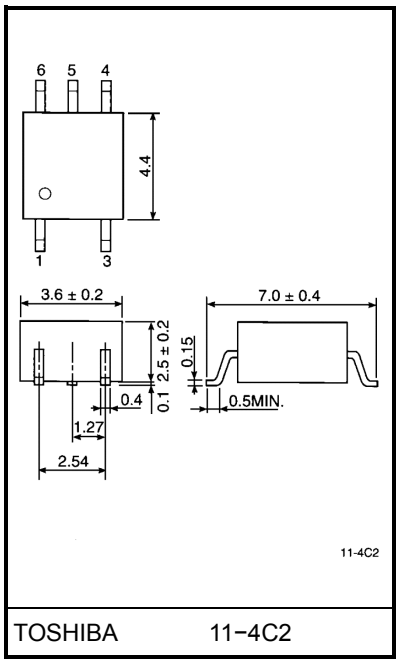
TLP130

Programmable Controllers

AC / DC−Input Module

Telecommunication

Unit in mm



TOSHIBA 11−4C2

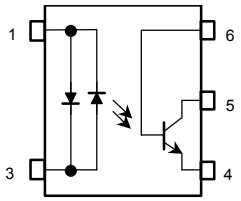
Weight: 0.09 g

The TOSHIBA mini flat coupler TLP130 is a small outline coupler, suitable for surface mount assembly.
TLP130 consists of a photo transistor, optically coupled to two gallium arsenide infrared emitting diode connected inverse parallel, and operate directly by AC input current.

- Collector−emitter voltage: 80V(min.)
- Current transfer ratio: 50%(min.)
  Rank GB: 100%(min.)
- Isolation voltage: 3750Vrms(min.)
- UL recognized: UL1577, file no.E67349
- Current transfer ratio

Classi−fication	Current Transfer Ratio I_F = 5mA, V_{CE} = 5V, Ta = 25°C		Marking Of Classification
	Min.	Max.	
Standard	50	600	Blank, Y, GR, GB
Rank GB	100	600	GB,GR

(Note) Application type name for certification test, please use standard puroduct type name, i.e. TLP130(GB): TLP130



1 : Anode, Cathode
3 : Cathode, Anode
4 : Emitter
5 : Collector
6 : Base

Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current	$I_{F(RMS)}$	50	mA
	Forward current derating (Ta≥53°C)	ΔI_F / °C	−0.7	mA / °C
	Peak forward current (100μs pulse,100pps)	I_{FP}	1	A
	Junction temperature	T_j	125	°C
Detector	Collector−emitter voltage	V_{CEO}	80	V
	Collector−base voltage	V_{CBO}	80	V
	Emitter−collector voltage	V_{ECO}	7	V
	Emitter−base voltage	V_{EBO}	7	V
	Collector current	I_C	50	mA
	Peak collector current (10ms pulse,100pps)	I_{CP}	100	mA
	Power dissipation	P_C	150	mW
	Power dissipation derating (Ta≥25°C)	ΔP_C / °C	−1.5	mW / °C
	Junction temperature	T_j	125	°C
Storage temperature range		T_{stg}	−55~125	°C
Operating temperature range		T_{opr}	−55~100	°C
Lead soldering temperature (10s)		T_{sol}	260	°C
Total package power dissipation		P_T	200	mW
Total package power dissipation derating (Ta≥25°C)		ΔP_T / °C	−2.0	mW / °C
Isolation voltage (AC, 1min., RH ≤ 60%)	(Note 1)	BV_S	3750	Vrms

(Note 1) Device considered a two terminal device: Pins 1 and 3 shorted together and pins 4, 5 and 6 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	V_{CC}	—	5	48	V
Forward current	$I_{F(RMS)}$	—	16	25	mA
Collector current	I_C	—	1	10	mA
Operating temperature	T_{opr}	−25	—	85	°C

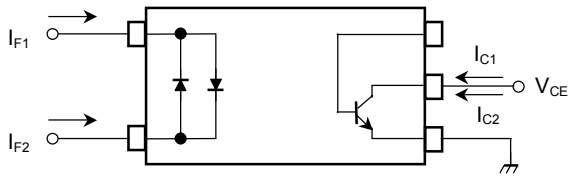
Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	V_F	I_F = ±10mA	1.0	1.15	1.3	V
	Capacitance	C_T	V = 0, f = 1MHz	—	60	—	pF
Detector	Collector−emitter breakdown voltage	$V_{(BR)CEO}$	I_C = 0.5mA	80	—	—	V
	Emitter−collector breakdown voltage	$V_{(BR)ECO}$	I_E = 0.1mA	7	—	—	V
	Collector−base breakdown voltage	$V_{(BR)CBO}$	I_C = 0.1mA	80	—	—	V
	Emitter−base breakdown voltage	$V_{(BR)EBO}$	I_E = 0.1mA	7	—	—	V
	Collector dark current	I_{CEO}	V_{CE} = 48V	—	10	100	nA
			V_{CE} = 48V, Ta = 85°C	—	2	50	μA
	Collector dark current	I_{CER}	V_{CE} = 48V, Ta = 85°C R_{BE} = 1MΩ	—	0.5	10	μA
	Collector dark current	I_{CBO}	V_{CB} = 10V	—	0.1	—	nA
	DC forward current gain	h_{FE}	V_{CE} = 5V, I_C = 0.5mA	—	400	—	—
	Capacitance collector to emitter	C_{CE}	V = 0 , f = 1MHz	—	10	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Current transfer ratio	I_C / I_F	I_F = ±5mA, V_{CE} = 5V	50	—	600	%
		Rank GB	100	—	600	
Saturated CTR	I_C / $I_{F(sat)}$	I_F = ±1mA, V_{CE} = 0.4V	—	60	—	%
		Rank GB	30	—	—	
Base photo−current	I_{PB}	I_F = ±5mA, V_{CB} = 5V	—	10	—	μA
Collector-emitter saturation voltage	$V_{CE(sat)}$	I_C = 2.4mA, I_F = ±8mA	—	—	0.4	V
		I_C = 0.2mA, I_F = ±1mA	—	0.2	—	
		Rank GB	—	—	0.4	
Off−state collector current	$I_{C(off)}$	I_F = ±0.7mA, V_{CE} = 48V	—	1	10	μA
CTR symmetry	$I_{C(ratio)}$	I_C(I_F = −5mA) / I_C(I_F = 5mA) (Note 2)	0.33	—	3	—

(Note 2) $I_{C(ratio)} = \dfrac{I_{C2}(I_F = I_{F2},\ V_{CE} = 5V)}{I_{C1}(I_F = I_{F1},\ V_{CE} = 5V)}$



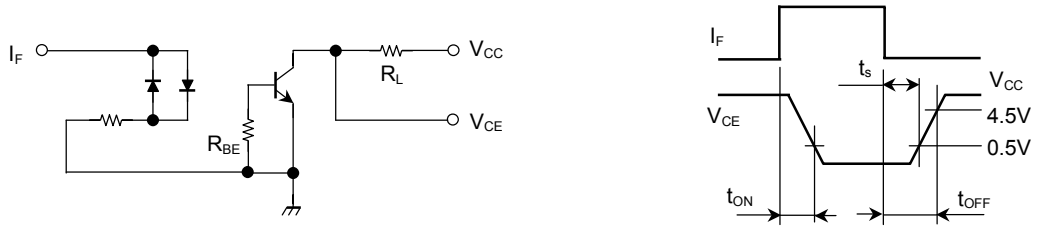
Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Capacitance input to output	C_S	V_S=0, f=1MHz	—	0.8	—	pF
Isolation resistance	R_S	V_S=500V	5×10^{10}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1minute	3750	—	—	Vrms
		AC, 1second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	Vdc

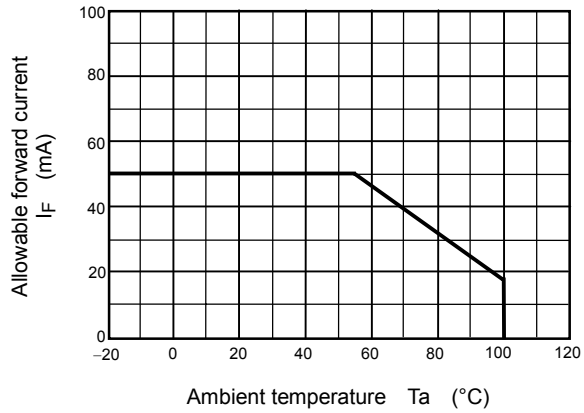
Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Rise time	t_r	V_{CC} = 10V, I_C = 2mA R_L = 100Ω	—	2	—	μs
Fall time	t_f		—	3	—	
Turn−on time	t_{on}		—	3	—	
Turn−off time	t_{off}		—	3	—	
Turn−on time	t_{ON}	R_L = 1.9 kΩ (Fig.1) R_{BE} = OPEN V_{CC} = 5 V, I_F = ±16mA	—	2	—	μs
Storage time	t_S		—	25	—	
Turn-off time	t_{OFF}		—	40	—	
Turn−on time	t_{ON}	R_L = 1.9kΩ (Fig.1) R_{BE} = 220kΩ V_{CC} = 5 V, I_F = ±16mA	—	2	—	μs
Storage time	t_S		—	20	—	
Turn-off time	t_{OFF}		—	30	—	

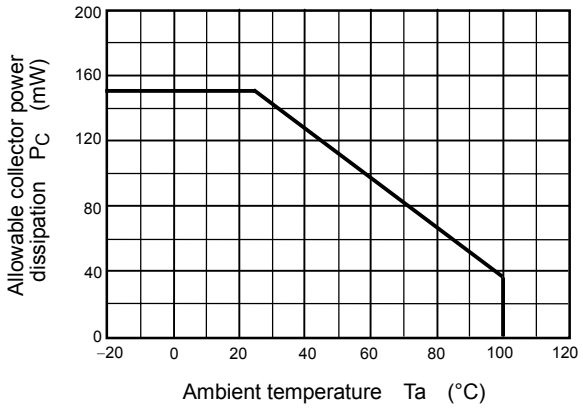
Fig. 1 Switching time test circuit



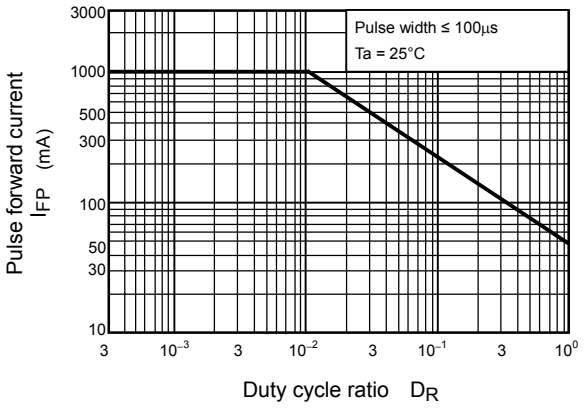
I_F – Ta



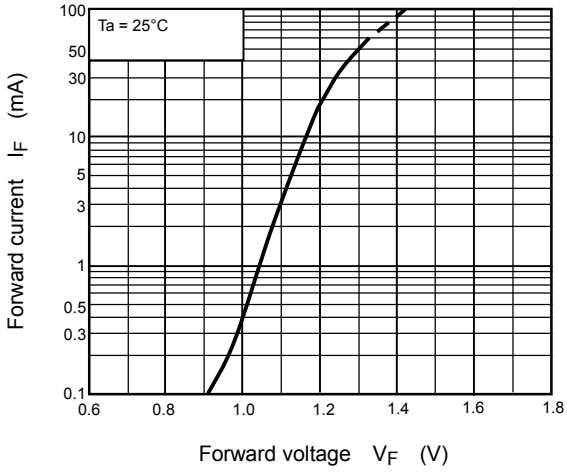
P_C – Ta



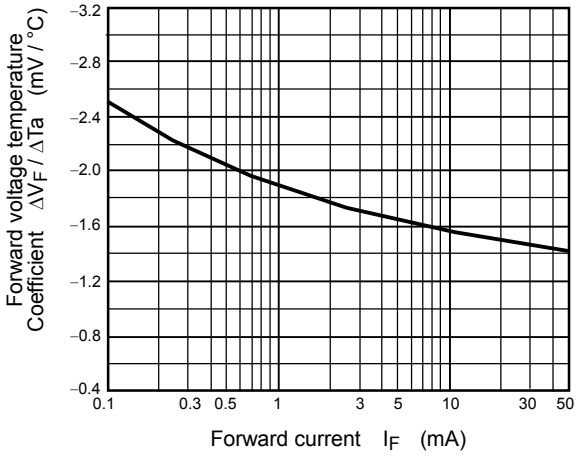
I_{FP} – D_R



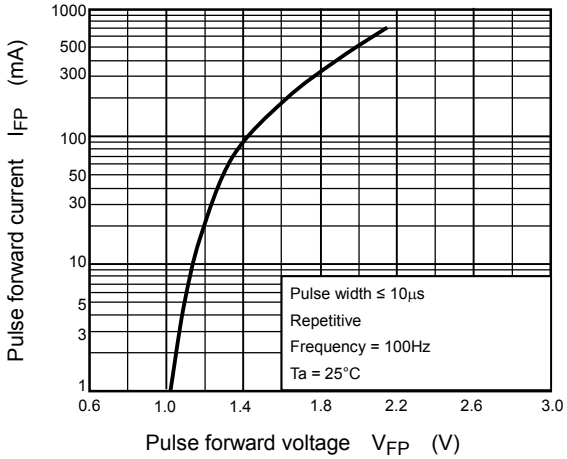
I_F – V_F



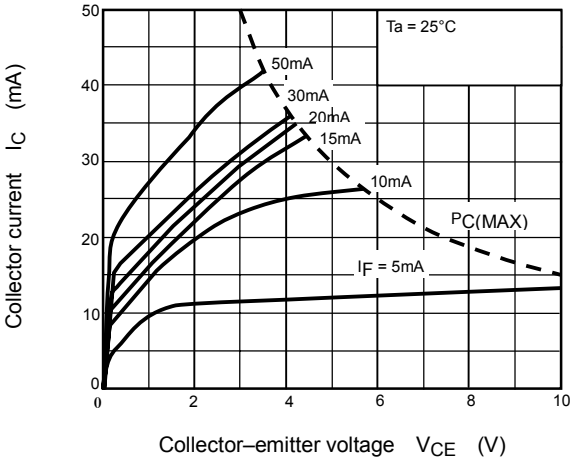
$\Delta V_F / \Delta Ta$ – I_F



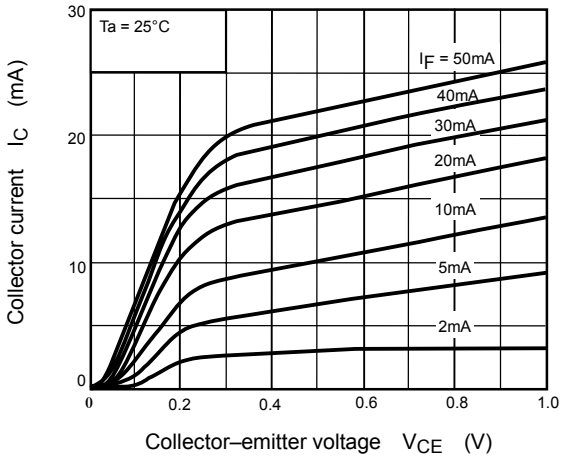
I_{FP} – V_{FP}



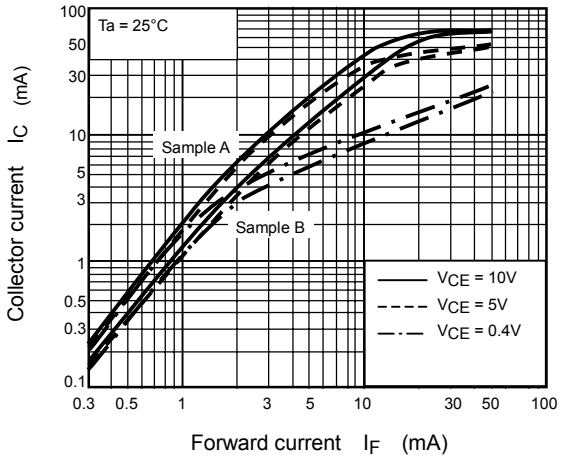
$I_C - V_{CE}$



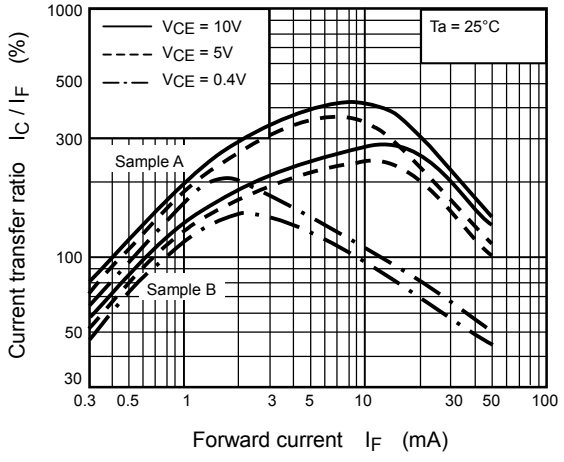
$I_C - V_{CE}$



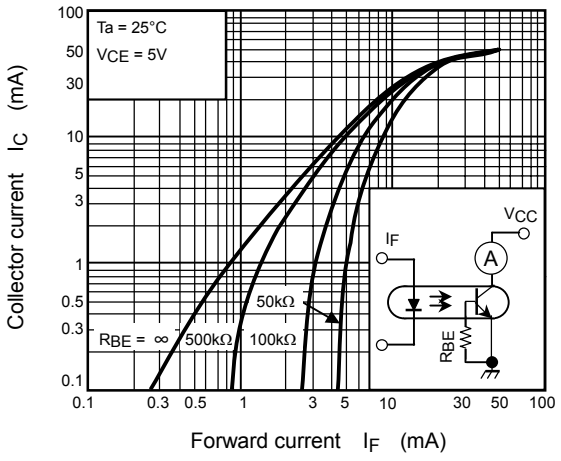
$I_C - I_F$



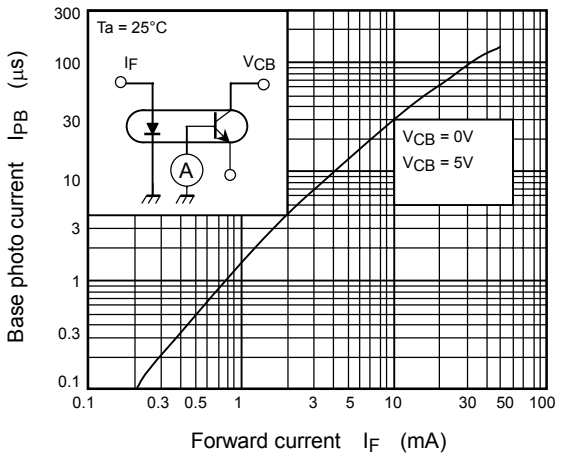
$I_C / I_F - I_F$



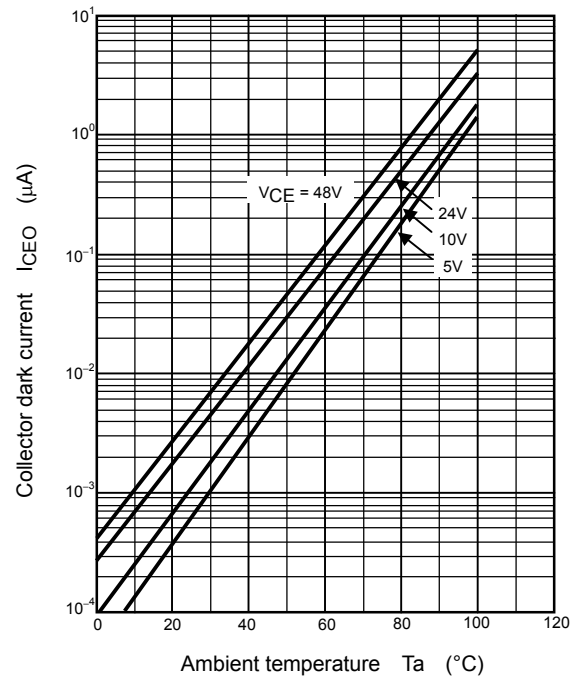
$I_C - I_F$ at R_{BE}



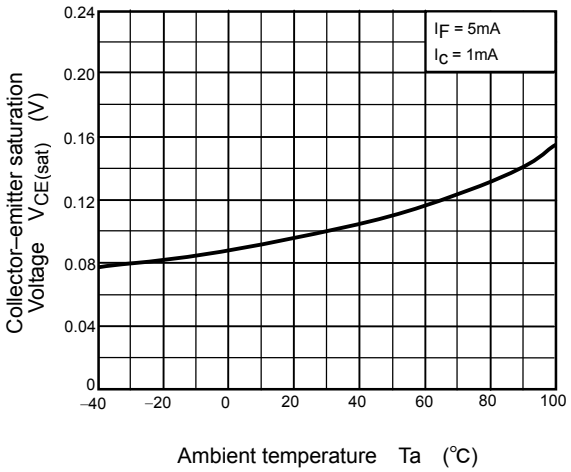
$I_{PB} - I_F$



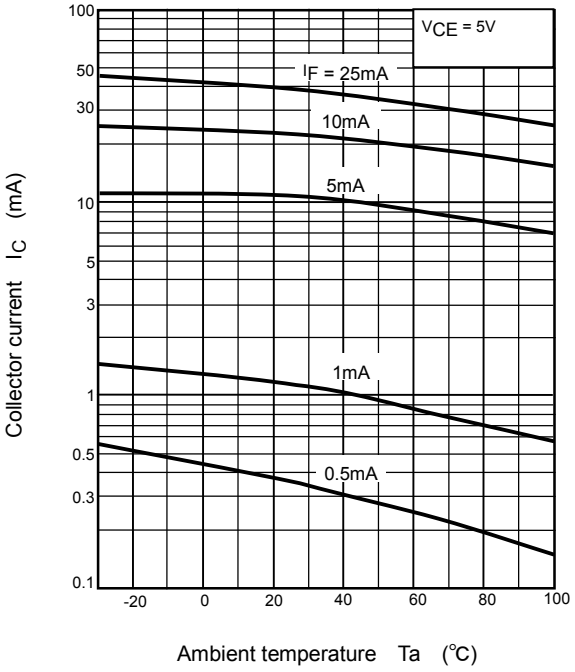
I_{CEO} – Ta



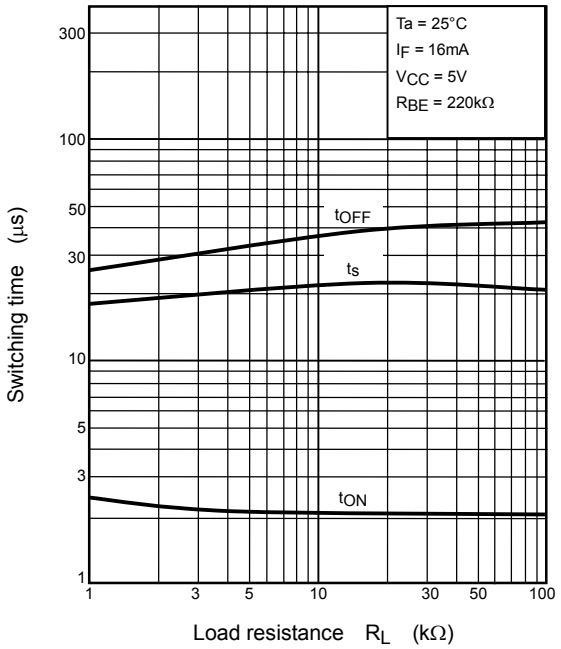
$V_{CE(sat)}$ – Ta



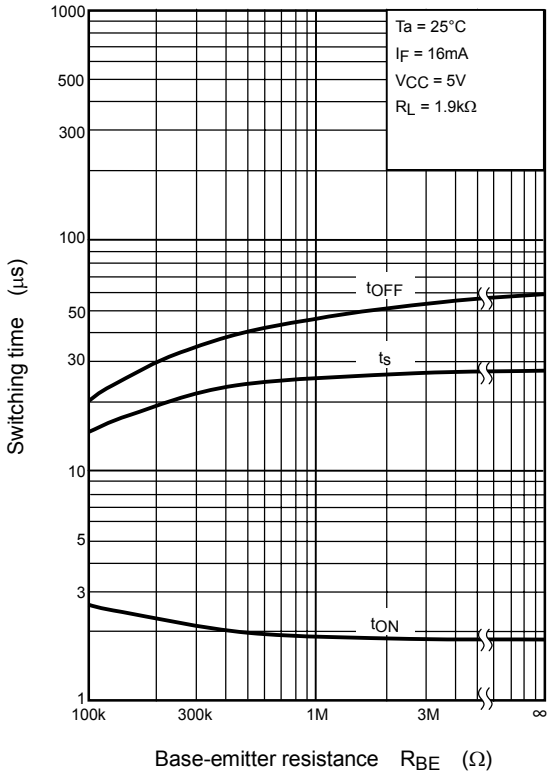
I_C – Ta



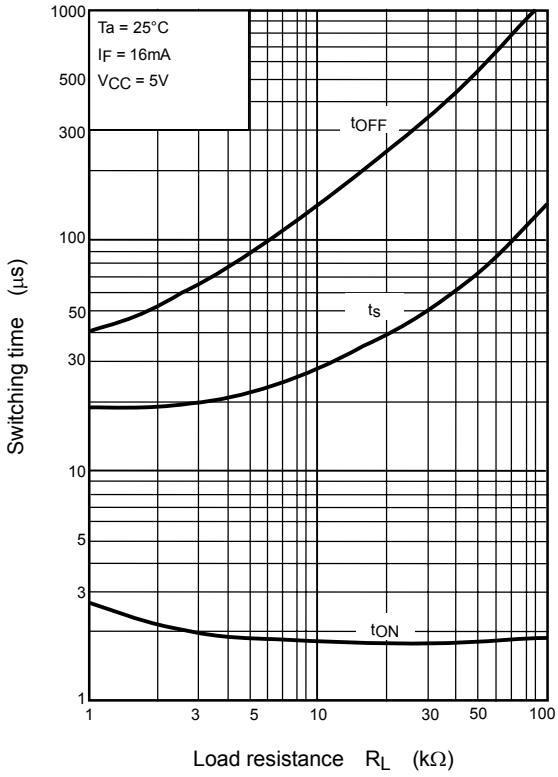
Switching Time – R_L



Switching Time – R_{BE}



Switching Time – R_L



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